

	<p><b>SPW35N60C3</b></p>
	<p><b>Hersteller-Teilenummer:</b> SPW35N60C3</p> <p><b>Hersteller / Marke:</b> International Rectifier (Infineon Technologies)</p> <p><b>Teil der Beschreibung:</b> SPW35N60C3 Infineon Technologies</p> <p><b>Datenblätter:</b>  <a href="#">SPW35N60C3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 15527 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SPW35N60C3
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	SPW35N60C3 Infineon Technologies
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	15527 pcs Stock
Serie	CoolMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	PG-TO247-3
Verlustleistung (max)	313W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	650V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	34.6A (Tc)
Rds On (Max) @ Id, Vgs	100 mOhm @ 21.9A, 10V
VGS (th) (Max) @ Id	3.9V @ 1.9mA
Gate Charge (Qg) (Max) @ Vgs	200nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	4500pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Tube

SPW35N60C3 ist neu im Original, Suche SPW35N60C3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SPW35N60C3 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage SPW35N60C3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>SPW47N60C2</b> International Rectifier (Infineon Technologies) SPW47N60C2 INFINEON</p>	 <p><b>SPW32N50C3</b> IGBT Module SPW32N50C3 IGBT Module</p>	 <p><b>SPW47N60C3</b> International Rectifier (Infineon Technologies) SPW47N60C3 Infineon Technologies</p>	 <p><b>SPW35N60CFD</b> INFINEO SPW35N60CFD INFINEO</p>
 <p><b>SPW35N60CFDFKSA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 600V 34.1A TO-247</p>	 <p><b>SPW32N50C3FKSA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 560V 32A TO-247</p>	 <p><b>SPW300A-EV151</b> SUNPLUS SUNPLUS QFN-44</p>	 <p><b>SPW24N60S5</b> INF SPW24N60S5 INF</p>

heiße Teile

Mehr

ADSP2115KS66	AWT6625RM45P9	CC0201BRNPO9BN2R7	CY7C68053-56BAXIT	HL0402-080M301NP1
LTC1874EGN	LTC4210-2IS6#TRPBF	MD4832-D512-V3Q18-X	MD56V62320K-75TA4P3A	P2507NF-C1
PC725V0NIPXF	PC8394T-VJG	RBS1MM40A	SKR26/08	SPW0430HR5HB
SPW07N60CFD	SPW11N60C3	SPW11N60CFD	SPW11N60S5	SPW11N80C3
SPW12N50C3	SPW1522WA	SPW1550COTR	SPW15N60C3	SPW15N60CFD
SPW16N50C3	SPW17N80C3	SPW20N60C2	SPW20N60C3	SPW20N60CFD
SPW20N60S5	SPW20N65C3	SPW21N50C3	SPW24N60C3	SPW24N60CFD
SPW32N50C3	SPW35N60CFD	SPW47N60C3	SPW47N60CFD	SPW47N60S5
SPW47N65C3	SPW48815-100-4	SPW48S12-100TH	SPW48S15-100-4	SPW48S24-100
SPW52N50C3	ST2000C16K1	UG2C-E3/73	UPD78F9234CS-CAA-A	ZM4730A-GS18

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